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November 2014

KSC2331 NPN Epitaxial Silicon Transistor

Features

- · Low-Frequency Amplifier and Medium Speed Switching
- · Complement to KSA931
- High Collector-Base Voltage: V_{CBO} = 80 V
- Collector Current: I_C = 700 mA



1. Emitter 2. Collector 3. Base

Ordering Information

Part Number	Top Mark	Package	Packing Method
KSC2331YTA	C2331 Y-	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	80	V
V _{CEO}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	8	V
I _C	Collector Current	700	mA
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Thermal Characteristics(1)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	1	W
	Derate Above 25°C	8.0	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

Note:

1. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	80			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{ mA}, I_B = 0$	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	8			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 60 \text{ V}, I_{E} = 0$			0.1	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 5 \text{ V}, I_{C} = 0$		\	0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = 2 \text{ V}, I_{C} = 50 \text{ mA}$	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.2	0.7	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.86	1.20	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 50 \text{ mA}$	30	50		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1 MHz		8		pF

h_{FE} Classification

Classification	R	0	Υ
h _{FF}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Performance Characteristics

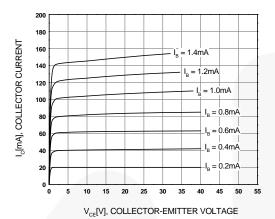


Figure 1. Static Characteristic

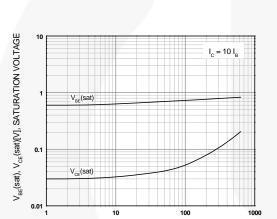


Figure 3. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

I_C[mA], COLLECTOR CURRENT

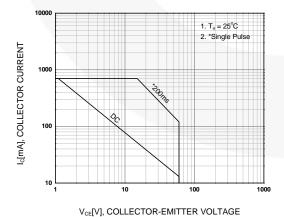


Figure 5. Safe Operating Area

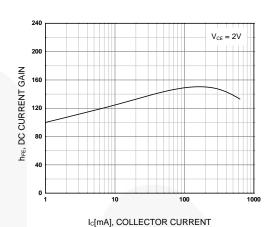


Figure 2. DC Current Gain

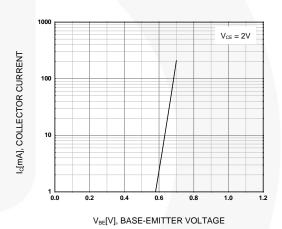


Figure 4. Base-Emitter On Voltage

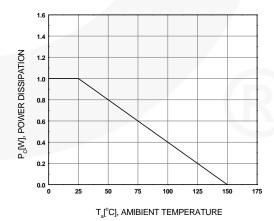
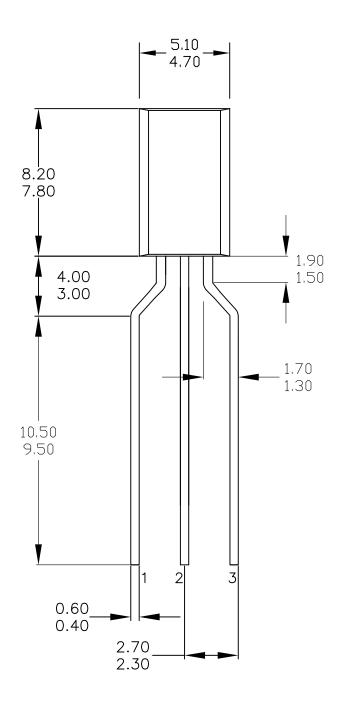
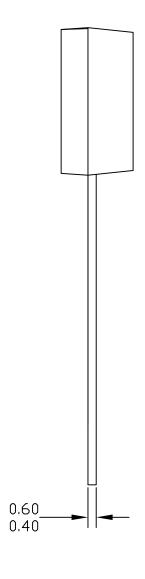
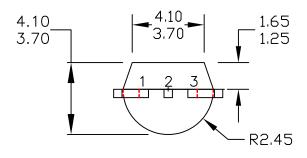


Figure 6. Power Derating







NOTES: UNLESS OTHERWISE SPECIFIED

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